



Welcome to [E-XFL.COM](#)

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	M32C/80
Core Size	16/32-Bit
Speed	32MHz
Connectivity	CANbus, I ² C, IEBus, SIO, UART/USART
Peripherals	DMA, WDT
Number of I/O	121
Program Memory Size	384KB (384K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 34x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LFQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30855fhgp-u5

1.2 Performance Overview

Tables 1.1 and 1.2 list performance overview of the M32C/85 group (M32C/85, M32C/85T).

Table 1.1 M32C/85 Group (M32C/85, M32C/85T) Performance (144-Pin Package)

Characteristic		Performance	
		M32C/85	M32C/85T
CPU	Basic Instructions	108 instructions	
	Minimum Instruction Execution Time	31.3 ns (f(BCLK)=32 MHz, Vcc1=4.2 V to 5.5 V) 41.7 ns (f(BCLK)=24 MHz, Vcc1=3.0 V to 5.5 V)	31.3 ns (f(BCLK)=32 MHz, Vcc1=4.2 V to 5.5 V)
	Operating Mode	Single-chip mode, Memory expansion mode and Microprocessor mode	Single-chip mode
	Address Space	16 Mbytes	
	Memory Capacity	See Table 1.3	
Peripheral Function	I/O Port	123 I/O pins and 1 input pin	
	Multifunction Timer	Timer A: 16 bits x 5 channels, Timer B: 16 bits x 6 channels Three-phase motor control circuit	
	Intelligent I/O	Time measurement function or Waveform generating function: 16 bits x 8 channels Communication function (Clock synchronous serial I/O, Clock asynchronous serial I/O, HDLC data processing)	
	Serial I/O	5 Channels Clock synchronous serial I/O, Clock asynchronous serial I/O, IEBus ⁽¹⁾ , I ² C bus ⁽²⁾	
	CAN Module	2 channels Supporting CAN 2.0B specification	
	A/D Converter	10-bit A/D converter: 1 circuit, 34 channels	
	D/A Converter	8 bits x 2 channels	
	DMAC	4 channels	
	DMAC II	Can be activated by all peripheral function interrupt sources Immediate transfer, Calculation transfer and Chain transfer functions	
	CRC Calculation Circuit	CRC-CCITT	
	X/Y Converter	16 bits x 16 bits	
	Watchdog Timer	15 bits x 1 channel (with prescaler)	
	Interrupt	39 internal and 8 external sources, 5 software sources Interrupt priority level: 7	
	Clock Generation Circuit	4 circuits Main clock oscillation circuit(*), Sub clock oscillation circuit(*), On-chip oscillator, PLL frequency synthesizer (*)Equipped with a built-in feedback resistor. Ceramic resonator or crystal oscillator must be connected externally	
	Oscillation Stop Detect Function	Main clock oscillation stop detect function	
	Voltage Detection Circuit	Available (optional)	Not available ⁽⁴⁾
Electrical Characteristics	Supply Voltage	Vcc1=4.2 V to 5.5 V, Vcc2=3.0 V to Vcc1 (f(BCLK)=32 MHz) Vcc1=3.0 V to 5.5 V, Vcc2=3.0 V to Vcc1 (f(BCLK)=24 MHz)	Vcc1=Vcc2=4.2 V to 5.5 V, (f(BCLK)=32 MHz) ⁽³⁾
	Power Consumption	28 mA (Vcc1=Vcc2=5 V, f(BCLK)=32 MHz) 22 mA (Vcc1=Vcc2=3.3 V, f(BCLK)=24 MHz) 10μA (Vcc1=Vcc2=5 V, f(BCLK)=32 kHz, in wait mode)	28 mA (Vcc1=Vcc2=5 V, f(BCLK)=32 MHz) 10μA (Vcc1=Vcc2=5 V, f(BCLK)=32 kHz, in wait mode)
Flash Memory	Program/Erase Supply Voltage	3.3 V ± 0.3 V or 5.0 V ± 0.5 V	
	Program and Erase Endurance	100 times (all space)	
Operating Ambient Temperature		-20 to 85°C -40 to 85°C (optional)	-40 to 85°C (T version)
Package		144-pin plastic molded LQFP	

NOTES:

1. IEBus is a trademark of NEC Electronics Corporation.
2. I²C bus is a trademark of Koninklijke Philips Electronics N. V.
3. The supply voltage of M32C/85T (High-reliability version) must be Vcc1=Vcc2.
4. The cold start-up/warm start-up determine function is available only at the user's option.

All options are on a request basis.

Table 1.4 Pin Characteristics for 144-Pin Package

Pin No.	Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin ⁽¹⁾
1		P96			TxD4/SDA4/SRx4/CAN1OUT		ANEX1	
2		P95			CLK4/CAN1IN/CAN1WU		ANEX0	
3		P94		TB4IN	CTS4/RTS4/SS4		DA1	
4		P93		TB3IN	CTS3/RTS3/SS3		DA0	
5		P92		TB2IN	TxD3/SDA3/SRx3D3			
6		P91		TB1IN	RxD3/SCL3/STxD3			
7		P90		TB0IN	CLK3			
8		P146						
9		P145						
10		P144						
11		P143				INPC17/OUTC17		
12		P142				INPC16/OUTC16		
13		P141				INPC15/OUTC15		
14		P140				INPC14/OUTC14		
15	BYTE							
16	CNVss							
17	XCIN	P87						
18	XCOUT	P86						
19	RESET							
20	XOUT							
21	Vss							
22	XIN							
23	Vcc1							
24		P85	NMI					
25		P84	INT2					
26		P83	INT1		CAN0IN/CAN1IN			
27		P82	INT0		CAN0OUT/CAN1OUT			
28		P81		TA4IN/U		INPC15/OUTC15		
29		P80		TA4OUT/U		ISRxD0		
30		P77		TA3IN	CAN0IN	INPC14/OUTC14/ISCLK0		
31		P76		TA3OUT	CAN0OUT	INPC13/OUTC13/ISTxD0		
32		P75		TA2IN/W		INPC12/OUTC12/ISRxD1/BE1IN		
33		P74		TA2OUT/W		INPC11/OUTC11/ISCLK1		
34		P73		TA1IN/V	CTS2/RTS2/SS2	INPC10/OUTC10/ISTxD1/BE1OUT		
35		P72		TA1OUT/V	CLK2			
36		P71		TB5IN/TA0IN	RxD2/SCL2/STxD2	INPC17/OUTC17		
37		P70		TA0OUT	TxD2/SDA2/SRx2D2	INPC16/OUTC16		
38		P67			TxD1/SDA1/SRx1D1			
39	Vcc1							
40		P66			RxD1/SCL1/STxD1			
41	Vss							
42		P65			CLK1			
43		P64			CTS1/RTS1/SS1			
44		P63			TxD0/SDA0/SRx0D0			
45		P62			RxD0/SCL0/STxD0			
46		P61			CLK0			
47		P60			CTS0/RTS0/SS0			
48		P137						

NOTES:

1. Bus control pins in M32C/85T cannot be used.

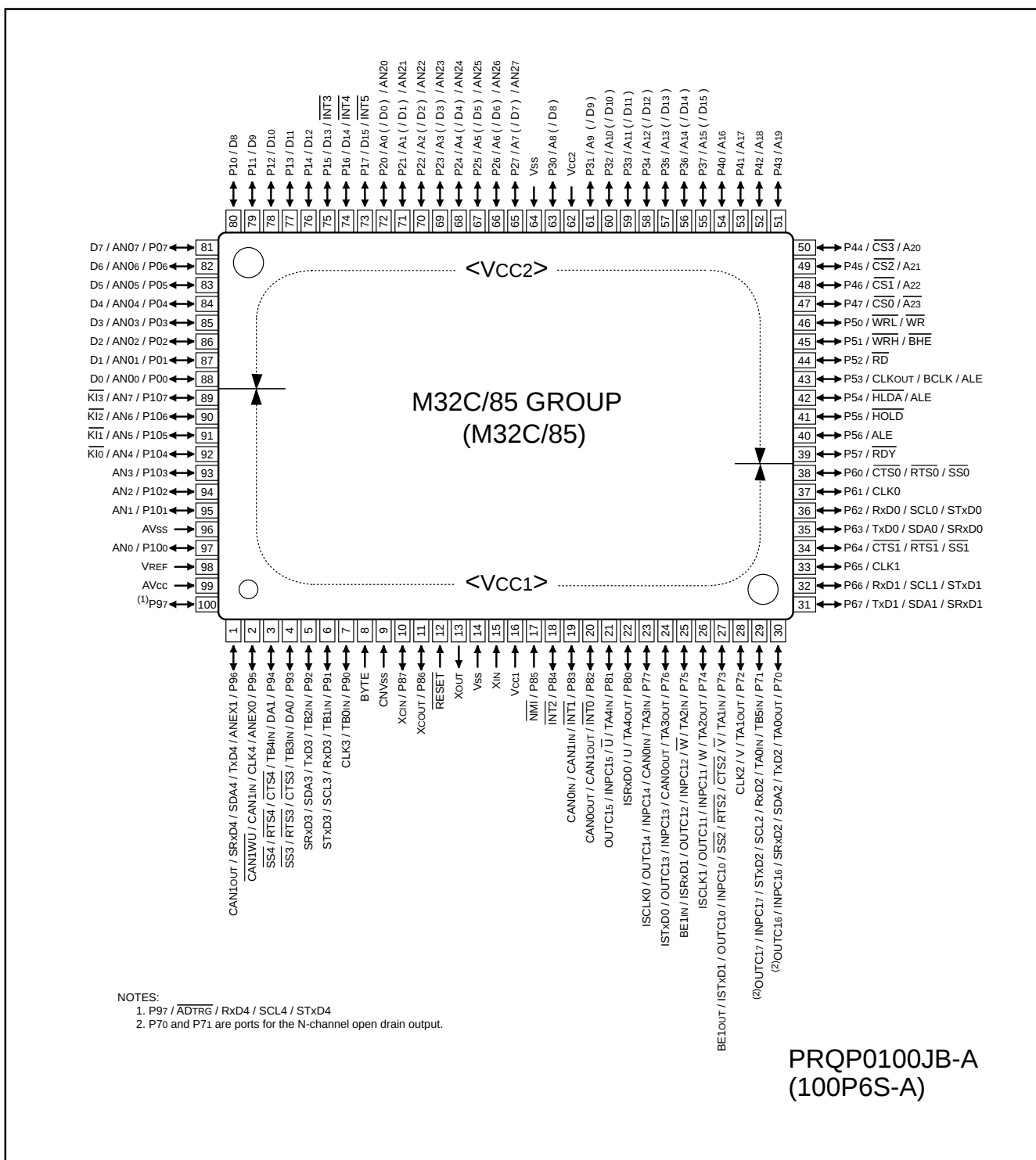


Figure 1.5 Pin Assignment for 100-Pin Package

Table 1.6 Pin Description (100-Pin and 144-Pin Packages) (Continued)

Classsification	Symbol	I/O Type	Supply Voltage	Function
Reference Voltage Input	VREF	I	-	Applies reference voltage to the A/D converter and D/A converter
A/D Converter	AN0 to AN7 AN00 to AN07 AN20 to AN27	I	Vcc1	Analog input pins for the A/D converter
	ADTRG	I	Vcc1	Input pin for an external A/D trigger
	ANEX0	I/O	Vcc1	Extended analog input pin for the A/D converter and output pin in external op-amp connection mode
	ANEX1	I	Vcc1	Extended analog input pin for the A/D converter
D/A Converter	DA0, DA1	O	Vcc1	Output pin for the D/A converter
Intelligent I/O	INPC10 to INPC13	I	Vcc1/Vcc2 ⁽¹⁾	Input pins for the time measurement function
	INPC14 to INPC17		Vcc1	
	OUTC10 to OUTC13	O	Vcc1/Vcc2 ⁽¹⁾	Output pins for the waveform generating function (OUTC16 and OUTC17 assigned to P70 and P71 are pins for the N-channel open drain output.)
	OUTC14 to OUTC17		Vcc1	
	ISCLK0	I/O	Vcc1	Inputs and outputs the clock for the intelligent I/O communication function
	ISCLK1		Vcc1/Vcc2 ⁽¹⁾	
	ISRXD0	I	Vcc1	Inputs data for the intelligent I/O communication function
	ISRXD1		Vcc1/Vcc2 ⁽¹⁾	
	ISTXD0	O	Vcc1	Outputs data for the intelligent I/O communication function
	ISTXD1		Vcc1/Vcc2 ⁽¹⁾	
	BE1IN	I	Vcc1/Vcc2 ⁽¹⁾	Inputs data for the intelligent I/O communication function
	BE1OUT	O	Vcc1/Vcc2 ⁽¹⁾	Outputs data for the intelligent I/O communication function
CAN	CAN0IN	I	Vcc1	Input pin for the CAN communication function
	CAN1IN			
	CAN0OUT	O		Output pin for the CAN communication function
	CAN1OUT			
	CAN1WU	I		Input pin for the CAN1 wake-up interrupt
I/O Ports	P00 to P07 P10 to P17 P20 to P27 P30 to P37 P40 to P47 P50 to P57	I/O	Vcc2	I/O ports for CMOS. Each port can be programmed for input or output under the control of the direction register. An input port can be set, by program, for a pull-up resistor available or for no pull-up resistor available in 4-bit units
	P60 to P67 P70 to P77 P90 to P97 P100 to P107	I/O	Vcc1	I/O ports having equivalent functions to P0 (P70 and P71 are ports for the N-channel open drain output.)
	P80 to P84 P86, P87	I/O	Vcc1	I/O ports having equivalent functions to P0
Input Port	P85	I	Vcc1	Shares a pin with NMĪ. NMĪ input state can be got by reading P85

I : Input O : Output I/O : Input and output

NOTES:

1. Vcc2 is not available in the 100-pin package. Vcc1 only available.

4. Special Function Registers (SFR)

Address	Register	Symbol	Value after RESET
0000 ₁₆			
0001 ₁₆			
0002 ₁₆			
0003 ₁₆			
0004 ₁₆	Processor Mode Register ⁽¹⁾	PM0	1000 0000 ₂ (CNVss pin ="L") 0000 0011 ₂ (CNVss pin ="H")
0005 ₁₆	Processor Mode Register 1	PM1	00 ₁₆
0006 ₁₆	System Clock Control Register 0	CM0	0000 1000 ₂
0007 ₁₆	System Clock Control Register 1	CM1	0010 0000 ₂
0008 ₁₆			
0009 ₁₆	Address Match Interrupt Enable Register	AIER	00 ₁₆
000A ₁₆	Protect Register	PRCR	XXXX 0000 ₂
000B ₁₆	External Data Bus Width Control Register ⁽²⁾	DS	XXXX 1000 ₂ (BYTE pin ="L") XXXX 0000 ₂ (BYTE pin ="H")
000C ₁₆	Main Clock Division Register	MCD	XXX0 1000 ₂
000D ₁₆	Oscillation Stop Detection Register	CM2	00 ₁₆
000E ₁₆	Watchdog Timer Start Register	WDTS	XX ₁₆
000F ₁₆	Watchdog Timer Control Register	WDC	000X XXXX ₂
0010 ₁₆			
0011 ₁₆	Address Match Interrupt Register 0	RMAD0	000000 ₁₆
0012 ₁₆			
0013 ₁₆	Processor Mode Register 2	PM2	00 ₁₆
0014 ₁₆	Address Match Interrupt Register 1	RMAD1	000000 ₁₆
0015 ₁₆			
0016 ₁₆			
0017 ₁₆	Voltage Detection Register 2 ⁽²⁾	VCR2	00 ₁₆
0018 ₁₆	Address Match Interrupt Register 2	RMAD2	000000 ₁₆
0019 ₁₆			
001A ₁₆			
001B ₁₆	Voltage Detection Register 1 ⁽²⁾	VCR1	0000 1000 ₂
001C ₁₆	Address Match Interrupt Register 3	RMAD3	000000 ₁₆
001D ₁₆			
001E ₁₆			
001F ₁₆			
0020 ₁₆			
0021 ₁₆			
0022 ₁₆			
0023 ₁₆			
0024 ₁₆			
0025 ₁₆			
0026 ₁₆	PLL Control Register 0	PLC0	0001 X010 ₂
0027 ₁₆	PLL Control Register 1	PLC1	000X 0000 ₂
0028 ₁₆	Address Match Interrupt Register 4	RMAD4	000000 ₁₆
0029 ₁₆			
002A ₁₆			
002B ₁₆			
002C ₁₆	Address Match Interrupt Register 5	RMAD5	000000 ₁₆
002D ₁₆			
002E ₁₆			
002F ₁₆	Low Voltage Detection Interrupt Register ⁽²⁾	D4INT	00 ₁₆

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. The PM01 and PM00 bits in the PM0 register maintain values set before reset, even after software reset or watch-dog timer reset has been performed.
2. These registers in M32C/85T cannot be used.

Address	Register	Symbol	Value after RESET
0030 ₁₆			
0031 ₁₆			
0032 ₁₆			
0033 ₁₆			
0034 ₁₆			
0035 ₁₆			
0036 ₁₆			
0037 ₁₆			
0038 ₁₆ 0039 ₁₆ 003A ₁₆	Address Match Interrupt Register 6	RMAD6	000000 ₁₆
003B ₁₆			
003C ₁₆ 003D ₁₆ 003E ₁₆	Address Match Interrupt Register 7	RMAD7	000000 ₁₆
003F ₁₆			
0040 ₁₆			
0041 ₁₆			
0042 ₁₆			
0043 ₁₆			
0044 ₁₆			
0045 ₁₆			
0046 ₁₆			
0047 ₁₆			
0048 ₁₆	External Space Wait Control Register 0 ⁽¹⁾	EWCR0	X0X0 0011 ₂
0049 ₁₆	External Space Wait Control Register 1 ⁽¹⁾	EWCR1	X0X0 0011 ₂
004A ₁₆	External Space Wait Control Register 2 ⁽¹⁾	EWCR2	X0X0 0011 ₂
004B ₁₆	External Space Wait Control Register 3 ⁽¹⁾	EWCR3	X0X0 0011 ₂
004C ₁₆			
004D ₁₆			
004E ₁₆			
004F ₁₆			
0050 ₁₆			
0051 ₁₆			
0052 ₁₆			
0053 ₁₆			
0054 ₁₆			
0055 ₁₆ 0056 ₁₆	Flash Memory Control Register 1	FMR1	0000 0101 ₂
0057 ₁₆	Flash Memory Control Register 0	FMR0	0000 0001 ₂ (Flash memory version) XXXX XXX0 ₂ (Masked ROM version)
0058 ₁₆			
0059 ₁₆			
005A ₁₆			
005B ₁₆			
005C ₁₆			
005D ₁₆			
005E ₁₆			
005F ₁₆			

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. These registers cannot be used in M32C/85T.

Address	Register	Symbol	Value after RESET
01E0 ₁₆	CAN0 Message Slot Buffer 0 Standard ID0	C0SLOT0_0	XX ₁₆
01E1 ₁₆	CAN0 Message Slot Buffer 0 Standard ID1	C0SLOT0_1	XX ₁₆
01E2 ₁₆	CAN0 Message Slot Buffer 0 Extended ID0	C0SLOT0_2	XX ₁₆
01E3 ₁₆	CAN0 Message Slot Buffer 0 Extended ID1	C0SLOT0_3	XX ₁₆
01E4 ₁₆	CAN0 Message Slot Buffer 0 Extended ID2	C0SLOT0_4	XX ₁₆
01E5 ₁₆	CAN0 Message Slot Buffer 0 Data Length Code	C0SLOT0_5	XX ₁₆
01E6 ₁₆	CAN0 Message Slot Buffer 0 Data 0	C0SLOT0_6	XX ₁₆
01E7 ₁₆	CAN0 Message Slot Buffer 0 Data 1	C0SLOT0_7	XX ₁₆
01E8 ₁₆	CAN0 Message Slot Buffer 0 Data 2	C0SLOT0_8	XX ₁₆
01E9 ₁₆	CAN0 Message Slot Buffer 0 Data 3	C0SLOT0_9	XX ₁₆
01EA ₁₆	CAN0 Message Slot Buffer 0 Data 4	C0SLOT0_10	XX ₁₆
01EB ₁₆	CAN0 Message Slot Buffer 0 Data 5	C0SLOT0_11	XX ₁₆
01EC ₁₆	CAN0 Message Slot Buffer 0 Data 6	C0SLOT0_12	XX ₁₆
01ED ₁₆	CAN0 Message Slot Buffer 0 Data 7	C0SLOT0_13	XX ₁₆
01EE ₁₆	CAN0 Message Slot Buffer 0 Time Stamp High-Order	C0SLOT0_14	XX ₁₆
01EF ₁₆	CAN0 Message Slot Buffer 0 Time Stamp Low-Order	C0SLOT0_15	XX ₁₆
01F0 ₁₆	CAN0 Message Slot Buffer 1 Standard ID0	C0SLOT1_0	XX ₁₆
01F1 ₁₆	CAN0 Message Slot Buffer 1 Standard ID1	C0SLOT1_1	XX ₁₆
01F2 ₁₆	CAN0 Message Slot Buffer 1 Extended ID0	C0SLOT1_2	XX ₁₆
01F3 ₁₆	CAN0 Message Slot Buffer 1 Extended ID1	C0SLOT1_3	XX ₁₆
01F4 ₁₆	CAN0 Message Slot Buffer 1 Extended ID2	C0SLOT1_4	XX ₁₆
01F5 ₁₆	CAN0 Message Slot Buffer 1 Data Length Code	C0SLOT1_5	XX ₁₆
01F6 ₁₆	CAN0 Message Slot Buffer 1 Data 0	C0SLOT1_6	XX ₁₆
01F7 ₁₆	CAN0 Message Slot Buffer 1 Data 1	C0SLOT1_7	XX ₁₆
01F8 ₁₆	CAN0 Message Slot Buffer 1 Data 2	C0SLOT1_8	XX ₁₆
01F9 ₁₆	CAN0 Message Slot Buffer 1 Data 3	C0SLOT1_9	XX ₁₆
01FA ₁₆	CAN0 Message Slot Buffer 1 Data 4	C0SLOT1_10	XX ₁₆
01FB ₁₆	CAN0 Message Slot Buffer 1 Data 5	C0SLOT1_11	XX ₁₆
01FC ₁₆	CAN0 Message Slot Buffer 1 Data 6	C0SLOT1_12	XX ₁₆
01FD ₁₆	CAN0 Message Slot Buffer 1 Data 7	C0SLOT1_13	XX ₁₆
01FE ₁₆	CAN0 Message Slot Buffer 1 Time Stamp High-Order	C0SLOT1_14	XX ₁₆
01FF ₁₆	CAN0 Message Slot Buffer 1 Time Stamp Low-Order	C0SLOT1_15	XX ₁₆
0200 ₁₆ 0201 ₁₆	CAN0 Control Register 0	C0CTRL0	XX01 0X01 ₂ ⁽¹⁾ XXXX 0000 ₂ ⁽¹⁾
0202 ₁₆ 0203 ₁₆	CAN0 Status Register	C0STR	0000 0000 ₂ ⁽¹⁾ X000 0X01 ₂ ⁽¹⁾
0204 ₁₆ 0205 ₁₆	CAN0 Extended ID Register	C0IDR	00 ₁₆ ⁽¹⁾ 00 ₁₆ ⁽¹⁾
0206 ₁₆ 0207 ₁₆	CAN0 Configuration Register	C0CONR	0000 XXXX ₂ ⁽¹⁾ 0000 0000 ₂ ⁽¹⁾
0208 ₁₆ 0209 ₁₆	CAN0 Time Stamp Register	C0TSR	00 ₁₆ ⁽¹⁾ 00 ₁₆ ⁽¹⁾
020A ₁₆	CAN0 Transmit Error Count Register	C0TEC	00 ₁₆ ⁽¹⁾
020B ₁₆	CAN0 Receive Error Count Register	C0REC	00 ₁₆ ⁽¹⁾
020C ₁₆ 020D ₁₆	CAN0 Slot Interrupt Status Register	C0SISTR	00 ₁₆ ⁽¹⁾ 00 ₁₆ ⁽¹⁾
020E ₁₆			
020F ₁₆			

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. Values are obtained by setting the SLEEP bit in the C0SLPR register to "1" (sleep mode exited) after reset and applying the clock to the CAN module.

Address	Register	Symbol	Value after RESET
0210 ₁₆	CAN0 Slot Interrupt Mask Register	C0SIMKR	00 ₁₆ ⁽²⁾
0211 ₁₆			00 ₁₆ ⁽²⁾
0212 ₁₆			
0213 ₁₆			
0214 ₁₆	CAN0 Error Interrupt Mask Register	C0EIMKR	XXXX X000 ₂ ⁽²⁾
0215 ₁₆	CAN0 Error Interrupt Status Register	C0EISTR	XXXX X000 ₂ ⁽²⁾
0216 ₁₆	CAN0 Error Cause Register	C0EFR	00 ₁₆ ⁽²⁾
0217 ₁₆	CAN0 Baud Rate Prescaler	C0BRP	0000 0001 ₂ ⁽²⁾
0218 ₁₆			
0219 ₁₆	CAN0 Mode Register	C0MDR	XXXX XX00 ₂ ⁽²⁾
021A ₁₆			
021B ₁₆			
021C ₁₆			
021D ₁₆			
021E ₁₆			
021F ₁₆			
0220 ₁₆	CAN0 Single Shot Control Register	C0SSCTLR	00 ₁₆ ⁽²⁾
0221 ₁₆			00 ₁₆ ⁽²⁾
0222 ₁₆			
0223 ₁₆			
0224 ₁₆	CAN0 Single Shot Status Register	C0SSSTR	00 ₁₆ ⁽²⁾
0225 ₁₆			00 ₁₆ ⁽²⁾
0226 ₁₆			
0227 ₁₆			
0228 ₁₆	CAN0 Global Mask Register Standard ID0	C0GMR0	XXX0 0000 ₂ ⁽²⁾
0229 ₁₆	CAN0 Global Mask Register Standard ID1	C0GMR1	XX00 0000 ₂ ⁽²⁾
022A ₁₆	CAN0 Global Mask Register Extended ID0	C0GMR2	XXXX 0000 ₂ ⁽²⁾
022B ₁₆	CAN0 Global Mask Register Extended ID1	C0GMR3	00 ₁₆ ⁽²⁾
022C ₁₆	CAN0 Global Mask Register Extended ID2	C0GMR4	XX00 0000 ₂ ⁽²⁾
022D ₁₆			
022E ₁₆			
022F ₁₆			
0230 ₁₆	CAN0 Message Slot 0 Control Register / CAN0 Local Mask Register A Standard ID0	C0MCTL0/ C0LMAR0	0000 0000 ₂ ⁽²⁾ XXX0 0000 ₂ ⁽²⁾
0231 ₁₆	CAN0 Message Slot 1 Control Register / CAN0 Local Mask Register A Standard ID1	C0MCTL1/ C0LMAR1	0000 0000 ₂ ⁽²⁾ XX00 0000 ₂ ⁽²⁾
0232 ₁₆	CAN0 Message Slot 2 Control Register / CAN0 Local Mask Register A Extended ID0	C0MCTL2/ C0LMAR2	0000 0000 ₂ ⁽²⁾ XXXX 0000 ₂ ⁽²⁾
0233 ₁₆	CAN0 Message Slot 3 Control Register / CAN0 local Mask Register A Extended ID1	C0MCTL3/ C0LMAR3	00 ₁₆ ⁽²⁾ 00 ₁₆ ⁽²⁾
0234 ₁₆	CAN0 Message Slot 4 Control Register / CAN0 Local Mask Register A Extended ID2	C0MCTL4/ C0LMAR4	0000 0000 ₂ ⁽²⁾ XX00 0000 ₂ ⁽²⁾
0235 ₁₆	CAN0 Message Slot 5 Control Register	C0MCTL5	00 ₁₆ ⁽²⁾
0236 ₁₆	CAN0 Message Slot 6 Control Register	C0MCTL6	00 ₁₆ ⁽²⁾
0237 ₁₆	CAN0 Message Slot 7 Control Register	C0MCTL7	00 ₁₆ ⁽²⁾
0238 ₁₆	CAN0 Message Slot 8 Control Register / CAN0 Local Mask Register B Standard ID0	C0MCTL8/ C0LMBR0	0000 0000 ₂ ⁽²⁾ XXX0 0000 ₂ ⁽²⁾
0239 ₁₆	CAN0 Message Slot 9 Control Register / CAN0 Local Mask Register B Standard ID1	C0MCTL9/ C0LMBR1	0000 0000 ₂ ⁽²⁾ XX00 0000 ₂ ⁽²⁾

(Note 1)

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. The BANKSEL bit in the C0CTLR1 register switches functions for addresses 0220₁₆ to 023F₁₆.
2. Values are obtained by setting the SLEEP bit in the C0SLPR register to "1" (sleep mode exited) after reset and applying the clock to the CAN module.

<144-pin package>

Address	Register	Symbol	Value after RESET
03A0 ₁₆	Function Select Register A8	PS8	X000 0000 ₂
03A1 ₁₆	Function Select Register A9	PS9	00 ₁₆
03A2 ₁₆			
03A3 ₁₆			
03A4 ₁₆			
03A5 ₁₆			
03A6 ₁₆			
03A7 ₁₆	Function Select Register D1	PSD1	X0XX XX00 ₂
03A8 ₁₆			
03A9 ₁₆			
03AA ₁₆			
03AB ₁₆			
03AC ₁₆	Function Select Register C2	PSC2	XXXX X00X ₂
03AD ₁₆	Function Select Register C3	PSC3	X0XX XXXX ₂
03AE ₁₆			
03AF ₁₆	Function Select Register C	PSC	00X0 0000 ₂
03B0 ₁₆	Function Select Register A0	PS0	00 ₁₆
03B1 ₁₆	Function Select Register A1	PS1	00 ₁₆
03B2 ₁₆	Function Select Register B0	PSL0	00 ₁₆
03B3 ₁₆	Function Select Register B1	PSL1	00 ₁₆
03B4 ₁₆	Function Select Register A2	PS2	00X0 0000 ₂
03B5 ₁₆	Function Select Register A3	PS3	00 ₁₆
03B6 ₁₆	Function Select Register B2	PSL2	00X0 0000 ₂
03B7 ₁₆	Function Select Register B3	PSL3	00 ₁₆
03B8 ₁₆			
03B9 ₁₆	Function Select Register A5	PS5	XXX0 0000 ₂
03BA ₁₆			
03BB ₁₆			
03BC ₁₆			
03BD ₁₆			
03BE ₁₆			
03BF ₁₆			
03C0 ₁₆	Port P6 Register	P6	XX ₁₆
03C1 ₁₆	Port P7 Register	P7	XX ₁₆
03C2 ₁₆	Port P6 Direction Register	PD6	00 ₁₆
03C3 ₁₆	Port P7 Direction Register	PD7	00 ₁₆
03C4 ₁₆	Port P8 Register	P8	XX ₁₆
03C5 ₁₆	Port P9 Register	P9	XX ₁₆
03C6 ₁₆	Port P8 Direction Register	PD8	00X0 0000 ₂
03C7 ₁₆	Port P9 Direction Register	PD9	00 ₁₆
03C8 ₁₆	Port P10 Register	P10	XX ₁₆
03C9 ₁₆	Port P11 Register	P11	XX ₁₆
03CA ₁₆	Port P10 Direction Register	PD10	00 ₁₆
03CB ₁₆	Port P11 Direction Register	PD11	XXX0 0000 ₂
03CC ₁₆	Port P12 Register	P12	XX ₁₆
03CD ₁₆	Port P13 Register	P13	XX ₁₆
03CE ₁₆	Port P12 Direction Register	PD12	00 ₁₆
03CF ₁₆	Port P13 Direction Register	PD13	00 ₁₆

X: Indeterminate

Blank spaces are reserved. No access is allowed.

5. Electrical Characteristics

5.1 Electrical Characteristics (M32C/85)

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Value	Unit
V _{CC1} , V _{CC2}	Supply Voltage		V _{CC1} =AV _{CC}	-0.3 to 6.0	V
V _{CC2}	Supply Voltage		-	-0.3 to V _{CC1}	V
AV _{CC}	Analog Supply Voltage		V _{CC1} =AV _{CC}	-0.3 to 6.0	V
V _I	Input Voltage	RESET, CNV _{SS} , BYTE, P60-P67, P72-P77, P80-P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾ , V _{REF} , X _{IN}		-0.3 to V _{CC1} +0.3	V
		P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137 ⁽¹⁾		-0.3 to V _{CC2} +0.3	
		P70, P71		-0.3 to 6.0	
V _O	Output Voltage	P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾ , X _{OUT}		-0.3 to V _{CC1} +0.3	V
		P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137 ⁽¹⁾		-0.3 to V _{CC2} +0.3	
		P70, P71		-0.3 to 6.0	
P _d	Power Dissipation		T _{opr} =25° C	500	mW
T _{opr}	Operating Ambient Temperature	during CPU operation		-20 to 85/ -40 to 85 ⁽²⁾	° C
		during flash memory program and erase operation		0 to 60	
T _{stg}	Storage Temperature			-65 to 150	° C

NOTES:

1. P11 to P15 are provided in the 144-pin package only.
2. Contact Renesas Technology Sales Co., Ltd, if temperature range of -40 to 85° C is required.

$$V_{CC1}=V_{CC2}=5V$$

Table 5.3 Electrical Characteristics(V_{CC1}=V_{CC2}=4.2 to 5.5V, V_{SS}=0V at Topr= -20 to 85°C, f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter		Condition		Standard			Unit	
					Min.	Typ.	Max.		
V _{OH}	Output High ("H") Voltage	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137		I _{OH} =-5mA		V _{CC2} -2.0		V _{CC2}	V
		P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾		I _{OH} =-5mA		V _{CC1} -2.0		V _{CC1}	
		P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137		I _{OH} =-200μA		V _{CC2} -0.3		V _{CC2}	V
		P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾		I _{OH} =-200μA		V _{CC1} -0.3		V _{CC1}	
		X _{OUT}		I _{OH} =-1mA		3.0		V _{CC1}	V
		X _{COUT}	High Power	No load applied		2.5			V
			Low Power	No load applied		1.6			
V _{OL}	Output Low ("L") Voltage	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾		I _{OL} =5mA				2.0	V
		P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾		I _{OL} =200μA				0.45	V
		X _{OUT}		I _{OL} =1mA				2.0	V
		X _{COUT}	High Power	No load applied		0		V	
			Low Power	No load applied		0			
V _{T+} -V _{T-}	Hysteresis	HOLD, RDY, TA0 _{IN} -TA4 _{IN} , TB0 _{IN} -TB5 _{IN} , INT0-INT5, AD _{TRG} , CTS0-CTS4, CLK0-CLK4, TA0 _{OUT} -TA4 _{OUT} , NMI, KI0-KI3, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4			0.2		1.0	V	
		RESET			0.2		1.8	V	
I _{IH}	Input High ("H") Current	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾ , X _{IN} , RESET, CNV _{SS} , BYTE		V _I =5V				5.0	μA
I _{IL}	Input Low ("L") Current	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾ , X _{IN} , RESET, CNV _{SS} , BYTE		V _I =0V				-5.0	μA
R _{PULLUP}	Pull-up Resistance	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾		V _I =0V	Flash Memory	30	50	167	kΩ
					Masked ROM	20	40	167	
R _{fXIN}	Feedback Resistance	X _{IN}					1.5		MΩ
R _{fXCIN}	Feedback Resistance	X _{CIN}					10		MΩ
V _{RAM}	RAM Standby Voltage	In stop mode				2.0			V

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$$V_{CC1}=V_{CC2}=5V$$

**Table 5.6 Flash Memory Version Electrical Characteristics (V_{CC1}=4.5 to 5.5V, 3.0 to 3.6V at
T_{opr}=0 to 60°C unless otherwise specified)**

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
-	Program and Erase Endurance ⁽²⁾		100			cycles
-	Word Program Time (V _{CC1} =5.0V, T _{opr} =25° C)			25	200	μs
-	Lock Bit Program Time			25	200	μs
-	Block Erase Time (V _{CC1} =5.0V, T _{opr} =25° C)	4-Kbyte Block		0.3	4	s
		8-Kbyte Block		0.3	4	s
		32-Kbyte Block		0.5	4	s
		64-Kbyte Block		0.8	4	s
-	All-Unlocked-Block Erase Time ⁽¹⁾				4 x <i>n</i>	s
t _{PS}	Wait Time to Stabilize Flash Memory Circuit				15	μs
-	Data Hold Time (T _{opr} =-40 to 85 ° C)		10			years

NOTES:

1. *n* denotes the number of block to be erased.

2. Number of program-erase cycles per block.

If Program and Erase Endurance is *n* cycle (*n*≠100), each block can be erased and programmed *n* cycles.

For example, if a 4-Kbyte block A is erased after programming a word data 2,048 times, each to a different address, this counts as one program and erase endurance. Data can not be programmed to the same address more than once without erasing the block. (rewrite prohibited).

$$V_{CC1}=V_{CC2}=5V$$

Switching Characteristics

($V_{CC} = 4.2$ to $5.5V$, $V_{SS} = 0V$ at $T_{opr} = -20$ to $85^{\circ}C$ unless otherwise specified)

Table 5.23 Memory Expansion Mode and Microprocessor Mode
(when accessing an external memory space with the multiplexed bus)

Symbol	Parameter	Measurement Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address Output Delay Time	See Figure 5.2		18	ns
$t_{h(BCLK-AD)}$	Address Output Hold Time (BCLK standard)		-3		ns
$t_{h(RD-AD)}$	Address Output Hold Time (RD standard) ⁽⁵⁾		(Note 1)		ns
$t_{h(WR-AD)}$	Address Output Hold Time (WR standard) ⁽⁵⁾		(Note 1)		ns
$t_{d(BCLK-CS)}$	Chip-Select Signal Output Delay Time			18	ns
$t_{h(BCLK-CS)}$	Chip-Select Signal Output Hold Time (BCLK standard)		-3		ns
$t_{h(RD-CS)}$	Chip-Select Signal Output Hold Time (RD standard) ⁽⁵⁾		(Note 1)		ns
$t_{h(WR-CS)}$	Chip-Select Signal Output Hold Time (WR standard) ⁽⁵⁾		(Note 1)		ns
$t_{d(BCLK-RD)}$	RD Signal Output Delay Time			18	ns
$t_{h(BCLK-RD)}$	RD Signal Output Hold Time		-5		ns
$t_{d(BCLK-WR)}$	WR Signal Output Delay Time			18	ns
$t_{h(BCLK-WR)}$	WR Signal Output Hold Time		-5		ns
$t_{d(DB-WR)}$	Data Output Delay Time (WR standard)		(Note 2)		ns
$t_{h(WR-DB)}$	Data Output Hold Time (WR standard) ⁽⁵⁾		(Note 1)		ns
$t_{d(BCLK-ALE)}$	ALE Signal Output Delay Time (BCLK standard)			18	ns
$t_{h(BCLK-ALE)}$	ALE Signal Output Hold Time (BCLK standard)		-2		ns
$t_{d(AD-ALE)}$	ALE Signal Output Delay Time (address standard)		(Note 3)		ns
$t_{h(ALE-AD)}$	ALE Signal Output Hold Time (address standard)		(Note 4)		ns
$t_{dZ(RD-AD)}$	Address Output Float Start Time			8	ns

NOTES:

1. Values can be obtained from the following equations, according to BCLK frequency.

$$t_{h(RD-AD)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$t_{h(WR-AD)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$t_{h(RD-CS)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$t_{h(WR-CS)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$t_{h(WR-DB)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

2. Values can be obtained from the following equations, according to BCLK frequency and external bus cycle.

$$t_{d(DB-WR)} = \frac{10^9 \times m}{f_{(BCLK)} \times 2} - 25 \quad [ns] \quad (\text{if external bus cycle is } a\phi + b\phi, m = (bx2)-1)$$

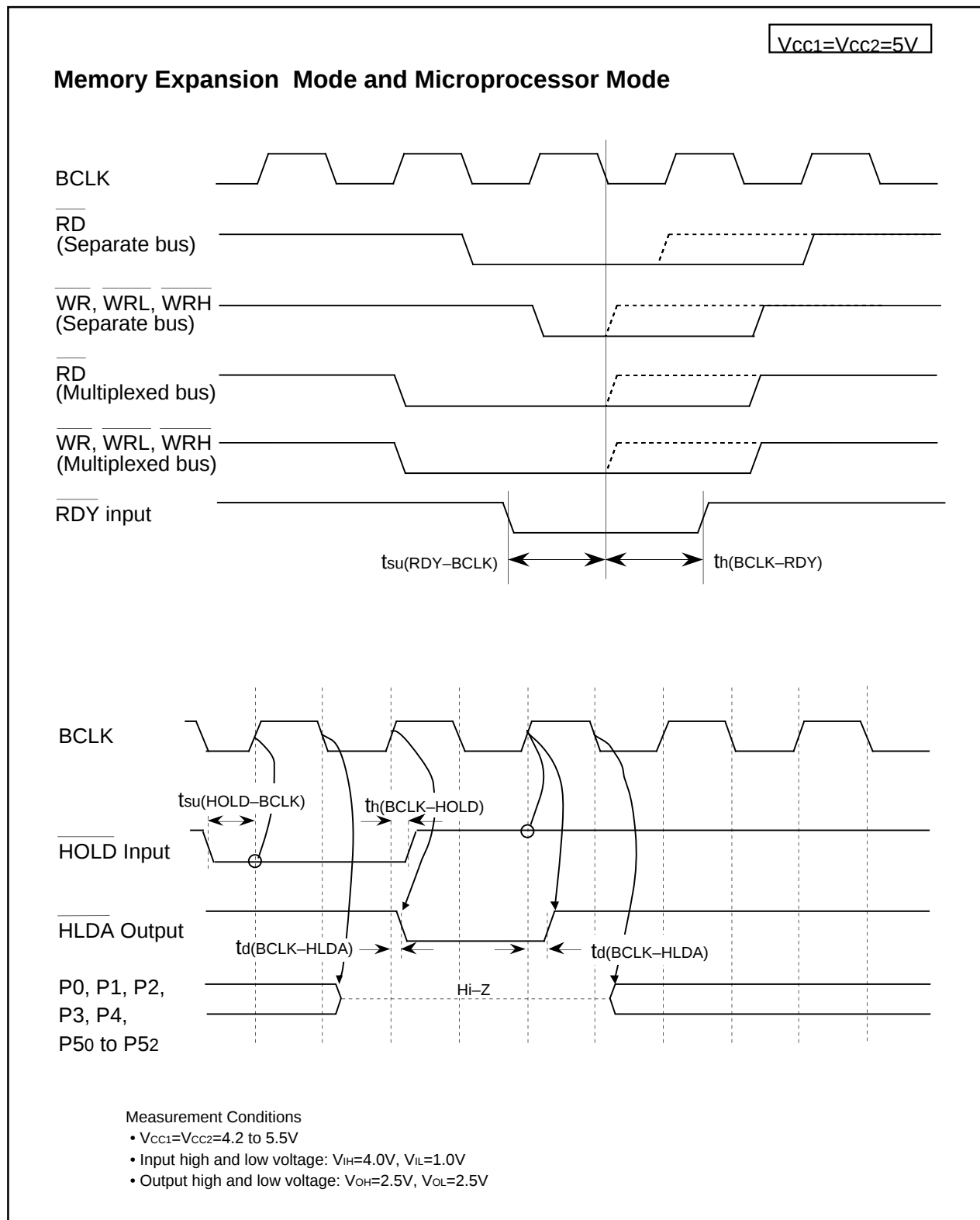
3. Values can be obtained from the following equations, according to BCLK frequency and external bus cycle.

$$t_{d(AD-ALE)} = \frac{10^9 \times n}{f_{(BCLK)} \times 2} - 20 \quad [ns] \quad (\text{if external bus cycle is } a\phi + b\phi, n = a)$$

4. Values can be obtained from the following equations, according to BCLK frequency and external bus cycle.

$$t_{h(ALE-AD)} = \frac{10^9 \times n}{f_{(BCLK)} \times 2} - 10 \quad [ns] \quad (\text{if external bus cycle is } a\phi + b\phi, n = a)$$

5. t_c ns is added when recovery cycle is inserted.

Figure 5.6 $V_{CC1}=V_{CC2}=5V$ Timing Diagram (4)

$$V_{CC1}=V_{CC2}=3.3V$$

Table 5.24 Electrical Characteristics ($V_{CC1}=V_{CC2}=3.0$ to $3.6V$, $V_{SS}=0V$ at $T_{opr} = -20$ to $85^{\circ}C$,
 $f(BCLK)=24MHz$ unless otherwise specified)

Symbol	Parameter			Condition		Standard			Unit
						Min.	Typ.	Max.	
V _{OH}	Output High ("H") Voltage	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137		I _{OH} =-1mA	V _{CC2} -0.6		V _{CC2}	V	
		P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾			V _{CC1} -0.6		V _{CC1}	V	
		X _{OUT}		I _{OH} =-0.1mA	2.7		V _{CC1}	V	
		X _{COUT}	High Power	No load applied		2.5		V	
			Low Power	No load applied		1.6		V	
V _{OL}	Output Low ("L") Voltage	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾		I _{OL} =1mA			0.5	V	
		X _{OUT}		I _{OL} =0.1mA			0.5	V	
		X _{COUT}	High Power	No load applied		0		V	
			Low Power	No load applied		0		V	
		V _{T+} -V _{T-}	Hysteresis	HOLD, RDY, TA0 _{IN} -TA4 _{IN} , TB0 _{IN} -TB5 _{IN} , INT0-INT5, AD _{TRG} , CTS0-CTS4, CLK0-CLK4, TA0 _{OUT} -TA4 _{OUT} , NMI, KI0-KI3, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4			0.2		1.0
		RESET			0.2		1.8	V	
I _{IH}	Input High ("H") Current	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾ , X _{IN} , RESET, CNV _{SS} , BYTE		V _I =3V			4.0	μA	
I _{IL}	Input Low ("L") Current	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾ , X _{IN} , RESET, CNV _{SS} , BYTE		V _I =0V			-4.0	μA	
R _{PULLUP}	Pull-up Resistance	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾		V _I =0V	Flash Memory	66	120	500	kΩ
					Masked ROM	40	70	500	kΩ
R _{fXIN}	Feedback Resistance	X _{IN}					3.0		MΩ
R _{fXCIN}	Feedback Resistance	X _{CIN}					20.0		MΩ
V _{RAM}	RAM Standby Voltage	in stop mode				2.0			V
I _{CC}	Power Supply Current	Measurement condition: In single-chip mode, output pins are left open and other pins are connected to V _{SS} .		f(BCLK)=24 MHz, Square wave, No division			22	35	mA
				f(BCLK)=32 kHz, In wait mode, T _{opr} =25° C			10		μA
				While clock stops, T _{opr} =25° C			0.8	5	μA
				While clock stops, T _{opr} =85° C				50	μA

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$$V_{CC1}=V_{CC2}=3.3V$$

Timing Requirements

($V_{CC1}=V_{CC2}=3.0$ to $3.6V$, $V_{SS}=0V$ at $T_{opr}=-20$ to $85^{\circ}C$ unless otherwise specified)

Table 5.27 External Clock Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External Clock Input Cycle Time	41		ns
$t_{w(H)}$	External Clock Input High ("H") Width	18		ns
$t_{w(L)}$	External Clock Input Low ("L") Width	18		ns
t_r	External Clock Rise Time		5	ns
t_f	External Clock Fall Time		5	ns

Table 5.28 Memory Expansion Mode and Microprocessor Mode

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{ac1(RD-DB)}$	Data Input Access Time (RD standard)		(Note 1)	ns
$t_{ac1(AD-DB)}$	Data Input Access Time (AD standard, CS standard)		(Note 1)	ns
$t_{ac2(RD-DB)}$	Data Input Access Time (RD standard, when accessing a space with the multiplexed bus)		(Note 1)	ns
$t_{ac2(AD-DB)}$	Data Input Access Time (AD standard, when accessing a space with the multiplexed bus)		(Note 1)	ns
$t_{su(DB-BCLK)}$	Data Input Setup Time	30		ns
$t_{su(RDY-BCLK)}$	$\overline{RDY}$ Input Setup Time	40		ns
$t_{su(HOLD-BCLK)}$	$\overline{HOLD}$ Input Setup Time	60		ns
$t_{h(RD-DB)}$	Data Input Hold Time	0		ns
$t_{h(BCLK-RDY)}$	$\overline{RDY}$ Input Hold Time	0		ns
$t_{h(BCLK-HOLD)}$	$\overline{HOLD}$ Input Hold Time	0		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ Output Delay Time		25	ns

NOTES:

1. Values can be obtained from the following equations, according to BCLK frequency and external bus cycles. Insert a wait state or lower the operation frequency, $f_{(BCLK)}$, if the calculated value is negative.

$$t_{ac1(RD-DB)} = \frac{10^9 \times m}{f_{(BCLK)} \times 2} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, m=(bx2)+1)$$

$$t_{ac1(AD-DB)} = \frac{10^9 \times n}{f_{(BCLK)}} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, n=a+b)$$

$$t_{ac2(RD-DB)} = \frac{10^9 \times m}{f_{(BCLK)} \times 2} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, m=(bx2)-1)$$

$$t_{ac2(AD-DB)} = \frac{10^9 \times p}{f_{(BCLK)} \times 2} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, p=\{(a+b-1)x2\}+1)$$

VCC1=VCC2=5V

Table 5.44 Electrical Characteristics (Continued)
(VCC1=VCC2=4.2 to 5.5V, VSS=0V at Topr = -40 to 85°C (T version),
f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
Icc	Power Supply Current	In single-chip mode, output pins are left open and other pins are connected to Vss.		28	50	mA
				430		μA
				25		μA
				10		μA
				0.8	5	μA
					50	μA

NOTES:

1. Value is obtained when setting the FMSTP bit in the FMR0 register to "1" (flash memory stopped).

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1}=V_{CC2}=4.2$ to $5.5V$, $V_{SS}=0V$ at $T_{opr}= -40$ to $85^{\circ}C$ (T version) unless otherwise specified)

Table 5.55 Timer B Input (Count Source Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TB _{IN} Input Cycle Time (counted on one edge)	100		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width (counted on one edge)	40		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width (counted on one edge)	40		ns
$t_{C(TB)}$	TB _{IN} Input Cycle Time (counted on both edges)	200		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width (counted on both edges)	80		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width (counted on both edges)	80		ns

Table 5.56 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TB _{IN} Input Cycle Time	400		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width	200		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width	200		ns

Table 5.57 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TB _{IN} Input Cycle Time	400		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width	200		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width	200		ns

Table 5.58 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	AD _{TRG} Input Cycle Time (required for trigger)	1000		ns
$t_{W(ADL)}$	AD _{TRG} Input Low ("L") Pulse Width	125		ns

Table 5.59 Serial I/O

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(CK)}$	CLK _I Input Cycle Time	200		ns
$t_{W(CKH)}$	CLK _I Input High ("H") Width	100		ns
$t_{W(CKL)}$	CLK _I Input Low ("L") Width	100		ns
$t_{d(C-Q)}$	TxD _I Output Delay Time		80	ns
$t_{h(C-Q)}$	TxD _I Hold Time	0		ns
$t_{su(D-C)}$	RxD _I Input Setup Time	30		ns
$t_{h(C-Q)}$	RxD _I Input Hold Time	90		ns

Table 5.60 External Interrupt INT_I Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{W(INH)}$	INT _I Input High ("H") Width	250		ns
$t_{W(INL)}$	INT _I Input Low ("L") Width	250		ns

REVISION HISTORY	M32C/85 Group (M32C/85, M32C/85T) Datasheet
------------------	---

Rev.	Date	Description	
		Page	Summary
0.30	Jul.18, 2003	–	New Document
0.40	Sep.30, 2003	2 to 3	Overview • Tables 1.1 and 1.2 M32C/85 Performance “Oscillator Stop Detect Function” added
		5	• Figure 1.2 ROM/RAM Capacity and Table 1.3. M32C/85 Group M30852ME-XXXGP and M30850ME-XXXGP/FP deleted
		6	• ROM capacity “192 Kbytes” deleted
0.40	Sep.30, 2003	7, 11, 12	• Figures 1.4 to 1.6 Pin Assignments Note 2 added
		10,14	- VREF pin changed from analog input pins to control pins.
		16 to 18	- SDA0 to SDA4 pins changed from output pins to I/O pins.
		17	- TA4OUT changed from input pin to I/O pin.
			- TA4IN pin changed from output pin to input pin.
		18	- ISRxD1 pin modified to ISRxD0 pin in port P8.
		19	- DA0 and DA1 pins changed from input pins to output pins.
0.40	Sep.30, 2003		- Symbol “P117” modified to “P114” and description from “8-bit” to “5-bit”.
			- Descriptions of ISTxD1 and BE1IN modified from “received data” to “transmit data”.
0.40	Sep.30, 2003		SFR
		44,45	- Notes written directly in the Tables.
0.50	Feb.05, 2004	2, 3	Overview • Tables 1.1 and 1.2 M32C/85 Performance “Shortest Instruction Execution Time” and “Power Consumption” values modified
		23	Memory • Figure 3.1 Memory Map Diagram modified
		24	SFR • “After RESET” values of PM 1, PM 2, D4INT, G0IRF, G1IRF, IDB0 to IDB1, TA0MR to TA4MR, TCSPR, DM0SL to DM3SL registers corrected
			• NOTES added to PM0 and TCSPR registers
0.50	Feb.05, 2004		Electrical Characteristics
			• Newly added
0.51	Feb.09, 2004		Electrical Characteristics
		52	• Table 5.6 Flash Memory Version Electrical Characteristics Note 4 changed
		59	• Figure 5.2 Vcc1=Vcc2=5V Timing Diagram (1) Notes 1 and 2 changed
		60	• Figure 5.3 Vcc1=Vcc2=5V Timing Diagram (2) Notes 1, 2, and 3 changed
		70	• Figure 5.6 Vcc1=Vcc2=3.3V Timing Diagram (1) Notes 1, 2, and 3 changed
		71	• Figure 5.7 Vcc1=Vcc2=3.3V Timing Diagram (2) Notes 1 and 2 changed
0.52	Mar.12, 2004		Overview
		2, 3	• Table 1.1 and 1.2 M32C/85 Group Performance Value of Power Consumption modified

REVISION HISTORY	M32C/85 Group (M32C/85, M32C/85T) Datasheet
------------------	---

Rev.	Date	Description	
		Page	Summary
		65	• Table 5.28 Memory Expansion Mode and Microprocessor Mode $t_{AC1}(AD-DB)$ expression modified
		77	• Table 5.44 Electrical Characteristics I_{CC} standard value revised
		80	• Table 5.47 Flash Memory Electrical Characteristics T_{opr} value modified
1.21	Jul.01, 2005	All pages	Package code changed: 144P6Q-A to PLQP0144KA-A, 100P6Q-A to PLQP0100KB-A, 100P6S-A to PRQP0100JB-A
		All pages	"Low Voltage Detection Reset" changed to "Brown-out Detection Reset"
			Special Function Register (SFR)
		27	• The G0RB register Value after reset modified
		39	• The TCSPR register Value after reset modified
			Electrical Characteristics
		47	• Table 5.2 Electrical Characteristics Parameter $f(BCLK)$ and its values added
		51	• Table 5.6 Flash Memory Version Electrical Characteristics Measurement condition changed
		53	• Table 5.10 Memory Expansion Mode and Microprocessor Mode $t_{AC1}(RD-DB)$ expression on Note 1 modified; $t_{AC2}(RD-DB)$ expression on Note 1 added
		59	• Figure 5.3 Vcc1=Vcc2=5V Timing Diagram (1) $t_{W(ER)}$ expression on Note 3 modified; t_{CYC} expression added
		60	• Figure 5.4 Vcc1=Vcc2=5V Timing Diagram (2) $t_{AC2}(AD-DB)$ expression on Note 1 modified; $t_{H(ALE-AD)}$ expressions on Notes 1 and 2 modified; t_{CYC} expression added
		65	• Table 5.28 Memory Expansion Mode and Microprocessor Mode $t_{AC1}(RD-DB)$ expression on Note 1 modified; $t_{AC2}(RD-DB)$ expression on Note 1 added
		70	• Figure 5.7 Vcc1=Vcc2=3.3V Timing Diagram (1) $t_{W(ER)}$ expression on Note 3 modified; t_{CYC} expression added
		71	• Figure 5.8 Vcc1=Vcc2=3.3V Timing Diagram (2) $t_{AC2}(RD-DB)$ expression on Note 1 modified; $t_{H(ALE-AD)}$ expressions on Notes 1 and 2 modified; $t_{H(WR-CS)}$ expression on Note 2 modified; t_{CYC} expression added
		76	• Table 5.43 Electrical Characteristics Parameter $f(BCLK)$ and its values added
		80	• Table 5.47 Flash Memory Version Electrical Characteristics Measurement condition changed